

# Ultraviolet selective thin film sensor

## TW30DY2

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### *Features*

- Schottky-type photodiode
- Intrinsic visible blindness due to wide-bandgap semiconductor material
- Built-in filter glass for low sensitivity above 400nm
- Large photoactive area
- No focusing lens needed, therefore large usable incident angle
- Designed to operate in photovoltaic mode
- TO-39 metal package

### *Maximum Ratings*

Parameter	Symbol	Value	Unit
Operating temperature range	$T_{opt}$	-20 ... +80	°C
Reverse voltage	$V_{Rmax}$	3	V
Forward current	$I_{Fmax}$	5	mA
Total power dissipation at 25°C	$P_{tot}$	5	mW

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### General Characteristics

( $T_a = 25\text{ °C}$ )

Parameter	Symbol	Value	Unit
Active area	A	15,66	mm <sup>2</sup>
Active area dimensions	L x W	5.4 x 2.9	mm <sup>2</sup>
Max. viewing angle	$\alpha$	app. 60	degree
Shunt resistance (dark)	$R_s$	100	M $\Omega$
Dark current at 10mV reverse bias	$I_d$	100	pA
Open circuit voltage (200 $\mu$ W/cm <sup>2</sup> , $\lambda=300$ nm)	$V_0$	>200	mV
Short circuit current (200 $\mu$ W/cm <sup>2</sup> , $\lambda=300$ nm)	$I_0$	564	nA
Breakdown voltage (dark)	$V_{BR}$	> 3	V

### Spectral Characteristics

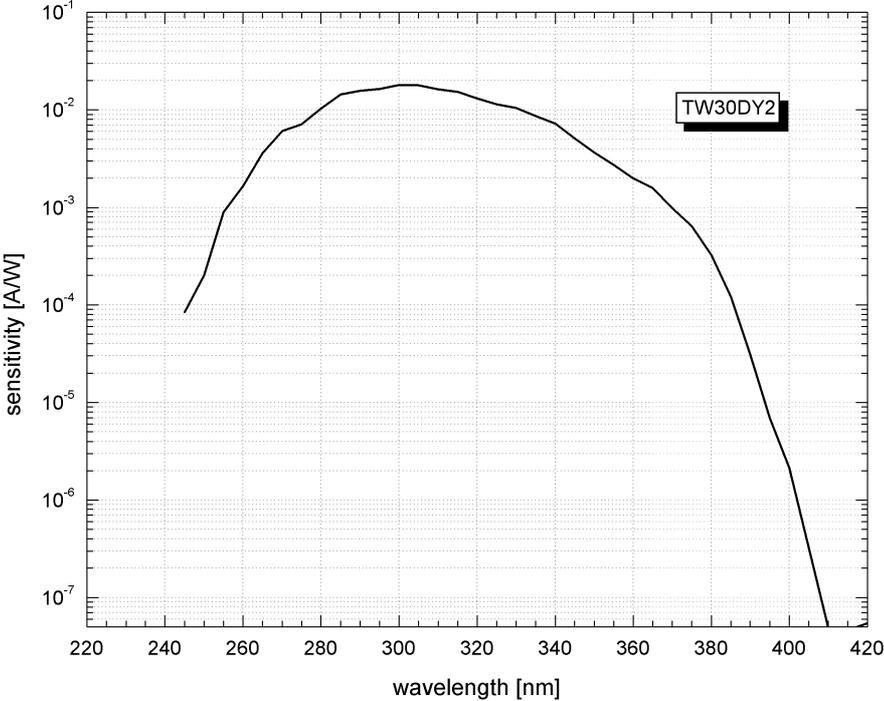
( $T_a = 25\text{ °C}$ )

Parameter	Symbol	typ. Value	Unit
Max. spectral sensitivity	$S_{max}$	18	mA W <sup>-1</sup>
Wavelength of max. spectral sensitivity	$\lambda_{Smax}$	300	nm
Range of spectral sensitivity ( $S=0.1*S_{max}$ )	-	260-362	nm
Visible blindness	$\frac{S_{max}}{S_{400nm}}$	10.000	

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### Spectral Response



### Pin Layout

